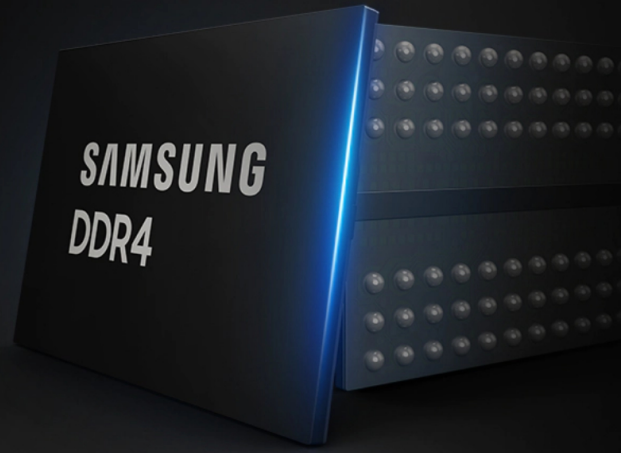




DDR4

Great performance for all solutions



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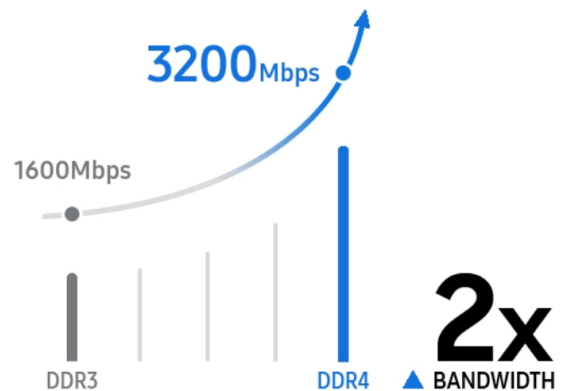
Exceptional speed, high reliability, low energy consumption

High-performing memory empowers faster, powerful solutions. Samsung DDR4 delivers top speed with better bandwidth and reliability using less energy.

An evolution in performance

- Increased bandwidth, up to 3,200 Mbps

Easily processing massive workloads with enhanced speed, the DDR4 transfers more data faster than ever before, offering 4 bank groups (total 16 banks) to reduce interleaving delays, plus 3,200 Mbps bandwidth and 1 TB/s system memory.



Less energy, greater efficiency

- Advanced process technology
- Reduce core and on/off power

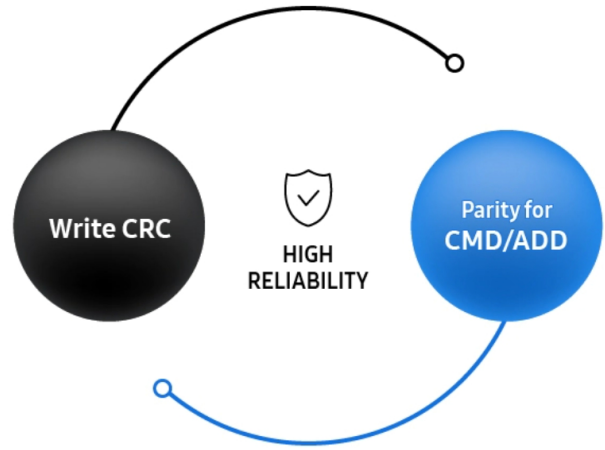


Samsung's industry-first 1x nm process technology enables DDR4 to consume less power while boosting performance, reducing TCO. The 1.2 V low operating voltage and Pseudo Open Drain (POD) interface enables lower power consumption, using 25% less energy.

Improved reliability

- Safe CRC transmission
- Parity bit to prevent errors

System reliability is ever more critical as data centers process ever more traffic. Advanced features of the Samsung DDR4 ensure superior data transmission, including Write CRC to help recognize multibit failures and parity checks for CMD/ADD to prevent system malfunctions.



Product selector

Density	Org.	Speed	Voltage	Temp.	Package
<input type="checkbox"/> 32 Gb	<input type="checkbox"/> 512M x 8	<input type="checkbox"/> 3200 Mbps	<input type="checkbox"/> 1.2 V	<input type="checkbox"/> 0 ~ 85 °C	<input type="checkbox"/> 96FBGA
<input type="checkbox"/> 16 Gb	<input type="checkbox"/> 512M x 16	<input type="checkbox"/> 2666 Mbps		<input type="checkbox"/> -40 ~ 95 °C	<input type="checkbox"/> 78FBGA
<input type="checkbox"/> 8 Gb	<input type="checkbox"/> 4G x 8	<input type="checkbox"/> 2400 Mbps			
<input type="checkbox"/> 4 Gb	<input type="checkbox"/> 2G x 8	<input type="checkbox"/> 2133 Mbps			
	<input type="checkbox"/> 2G x 4				
	<input type="checkbox"/> 2G x 16				
	<input type="checkbox"/> 256M x 16				
	<input type="checkbox"/> 1G x 8				
	<input type="checkbox"/> 1G x 16				

<input type="checkbox"/>	Part Number ▼	Density ▼	Org. ▼	Speed ▼	Voltage ▼	Temp. ▼	Package ▼
<input type="checkbox"/>	K4A4G085WE-BIRC	4 Gb	512M x 8	2400 Mbps	1.2 V	-40 ~ 95 °C	78FBGA
<input type="checkbox"/>	K4A4G085WE-BITD	4 Gb	512M x 8	2666 Mbps	1.2 V	-40 ~ 95 °C	78FBGA
<input type="checkbox"/>	K4A4G085WF-BCTD	4 Gb	512M x 8	2666 Mbps	1.2 V	0 ~ 85 °C	78FBGA

<input type="checkbox"/>	K4A4G085WF-BITD	4 Gb	512M x 8	2666 Mbps	1.2 V	-40 ~ 95 °C	78FBGA
<input type="checkbox"/>	K4A4G165WE-BCWE	4 Gb	256M x 16	3200 Mbps	1.2 V	0 ~ 85 °C	96FBGA
<input type="checkbox"/>	K4A4G165WE-BIRC	4 Gb	256M x 16	2400 Mbps	1.2 V	-40 ~ 95 °C	96FBGA
<input type="checkbox"/>	K4A4G165WE-BITD	4 Gb	256M x 16	2666 Mbps	1.2 V	-40 ~ 95 °C	96FBGA
<input type="checkbox"/>	K4A4G165WE-BIWE	4 Gb	256M x 16	3200 Mbps	1.2 V	-40 ~ 95 °C	96FBGA
<input type="checkbox"/>	K4A4G165WF-BCTD	4 Gb	256M x 16	2666 Mbps	1.2 V	0 ~ 85 °C	96FBGA
<input type="checkbox"/>	K4A4G165WF-BITD	4 Gb	256M x 16	2666 Mbps	1.2 V	-40 ~ 95 °C	96FBGA

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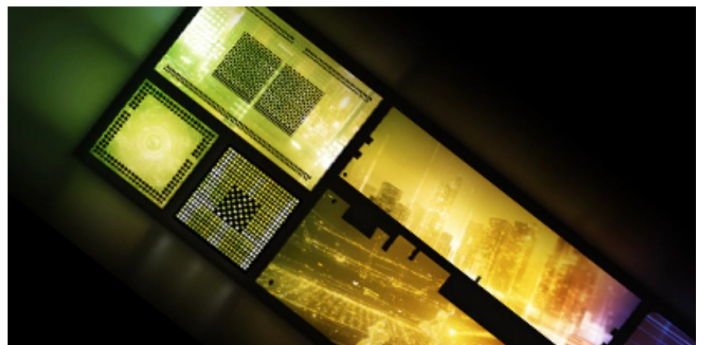
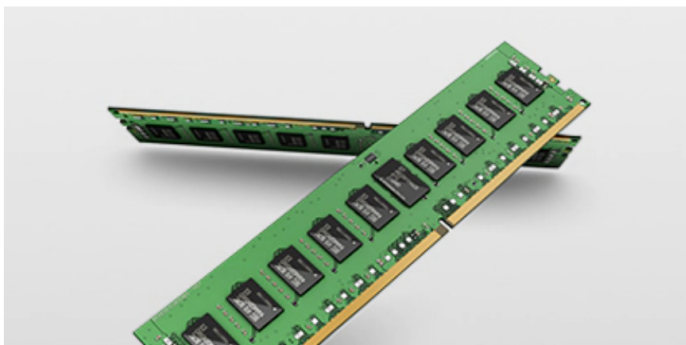


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